

# EYP-DFB-0773-00020-1500-BFY02-0x0x



We focus on power.

Revision 0.91

28.11.2011

page 1 from 5

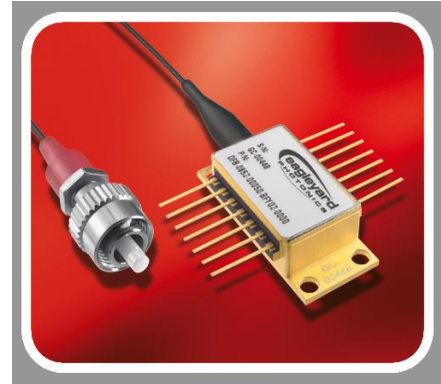
## DISTRIBUTED FEEDBACK LASER

GaAs Semiconductor Laser Diode with integrated grating structure



### General Product Information

Product	Application
773 nm DFB Laser with hermetic Butterfly Housing	Spectroscopy
Monitor Diode, Thermoelectric Cooler and Thermistor	Metrology
PM Fiber with angle-polished Connector	
High-reliable fully Space-qualified Package	



### Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	$T_S$	°C	-40		85
Operational Temperature at Case	$T_C$	°C	-40		85
Operational Temperature at Laser Chip	$T_{LD}$	°C	10		40
Forward Current	$I_F$	mA			150
Reverse Voltage	$V_R$	V			2
Output Power	$P_{opt}$	mW			25
TEC Current	$I_{TEC}$	A			1.8
TEC Voltage	$V_{TEC}$	V			3.2

Stress in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

### Recommended Operational Conditions

	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_C$	°C	-20		65
Operational Temperature at Laser Chip	$T_{LD}$	°C	15		35
Forward Current	$I_F$	mA			140
Output Power	$P_{opt}$	mW	5		20

#### Measurement Conditions / Comments

measured by integrated Thermistor

ex fiber

### Characteristics at $T_{LD} = 25\text{ °C}$ at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_C$	nm	772	773	774
Spectral Width (FWHM)	$\Delta\nu$	MHz		2	
Temperature Coefficient of Wavelength	$d\lambda / dT$	nm / K		0.06	
Current Coefficient of Wavelength	$d\lambda / dI$	nm / mA		0.003	
Output Power @ $I_F = 140\text{ mA}$	$P_{opt}$	mW	20		

#### Measurement Conditions / Comments

see images on page 4

ex fiber

# EYP-DFB-0773-00020-1500-BFY02-0x0x



We focus on power.

Revision 0.91

28.11.2011

page 2 from 5

## DISTRIBUTED FEEDBACK LASER

GaAs Semiconductor Laser Diode  
with integrated grating structure



### Characteristics at $T_{amb} = 25\text{ °C}$ at Begin Of Life cont'd

Parameter	Symbol	Unit	min	typ	max
Slope Efficiency	S	W / A	0.2	0.4	0.7
Threshold Current	$I_{th}$	mA			70
Sidemode Suppression Ratio	SMSR	dB	30	45	
Mode-hop free Temperature Range (SMSR > 30 dB)					
▶ Variant 0	$T_{LD}$	°C		25	
▶ Variant 1	$T_{LD}$	°C		25	
▶ Variant 2	$T_{LD}$	°C	15		35
Mode-hop free Power Range (SMSR > 30 dB)					
▶ Variant 0	$P_{opt}$	mW		20	
▶ Variant 1	$P_{opt}$	mW	5		20
▶ Variant 2	$P_{opt}$	mW	5		20
Polarization Extinction Ratio	PER	dB		20	
Spatial Mode (transversal)				TEM <sub>00</sub>	

#### Measurement Conditions / Comments

see below

Temperature at Laser Chip

see order code scheme on p. 5

SMSR > 30 dB

see order code scheme on p. 5

$P_{opt} = 20\text{ mW}$

fundamental mode

### Monitor Diode

Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	$I_{mon} / P_{opt}$	$\mu\text{A} / \text{mW}$	1		20
Reverse Voltage Monitor Diode	$U_{RMD}$	V	3		5

#### Measurement Conditions / Comments

$U_R = 5\text{ V}$ , target values

### Thermoelectric Cooler

Parameter	Symbol	Unit	min	typ	max
Current	$I_{TEC}$	A		0.4	
Voltage	$U_{TEC}$	V		0.8	
Power Dissipation (total loss at case)	$P_{loss}$	W		0.5	
Temperature Difference	$\Delta T$	K			50

#### Measurement Conditions / Comments

$P_{opt} = 20\text{ mW}$ ,  $\Delta T = 20\text{ K}$

$P_{opt} = 20\text{ mW}$ ,  $\Delta T = 20\text{ K}$

$P_{opt} = 20\text{ mW}$ ,  $\Delta T = 20\text{ K}$

$P_{opt} = 20\text{ mW}$ ,  $\Delta T = |T_{case} - T_{LD}|$

### Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kOhm		10	
Beta Coefficient	$\beta$			3892	

#### Measurement Conditions / Comments

# EYP-DFB-0773-00020-1500-BFY02-0x0x



We focus on power.

Revision 0.91

28.11.2011

page 3 from 5

## DISTRIBUTED FEEDBACK LASER

GaAs Semiconductor Laser Diode with integrated grating structure



### Fiber and Connector Type

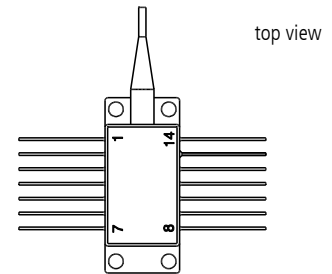
PM Fiber	900 / 125 / 5.5 $\mu$ m, UV/Polyester-elastomer Coating (l = 1 +/-0.1 m)
Connector	different variants available <ul style="list-style-type: none"> <li>▶ FC/APC (narrow key / 2mm)</li> <li>▶ SC/APC</li> <li>▶ other types on request</li> </ul>

### Measurement Conditions / Comments

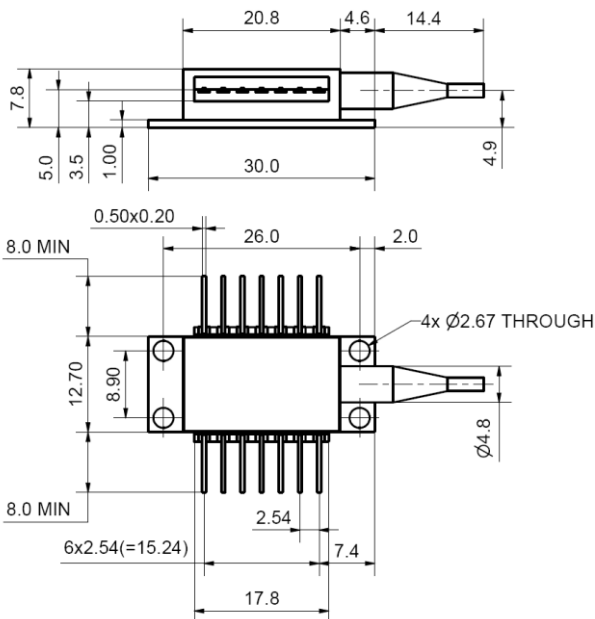
see order code scheme

### Package Pinout

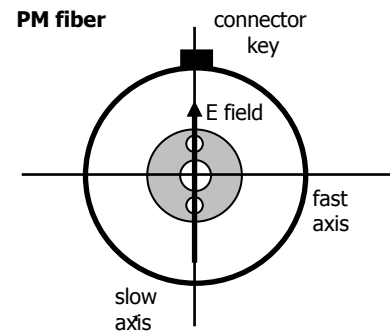
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected



### Package Drawings



recommended min. bending radius: 30 mm



slow axis of the PM fiber aligned to connector key

### hermetically sealed Package:

Leak Rate <math> < 5 \cdot 10^{-8}</math> atm.cc./s  
acc. MIL-STD-883E

Z11-SPEC-BFY02-DFB-0000

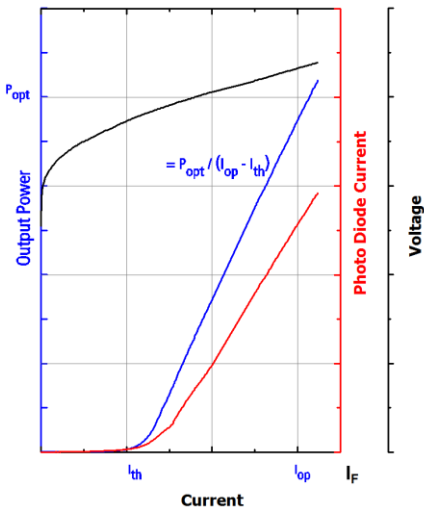
**DISTRIBUTED FEEDBACK LASER**

GaAs Semiconductor Laser Diode with integrated grating structure

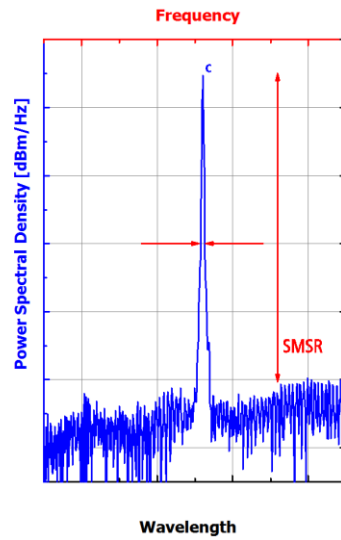


**Typical Measurement Results**

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

# EYP-DFB-0773-00020-1500-BFY02-0x0x



We focus on power.

Revision 0.91

28.11.2011

page 5 from 5

## DISTRIBUTED FEEDBACK LASER

GaAs Semiconductor Laser Diode with integrated grating structure



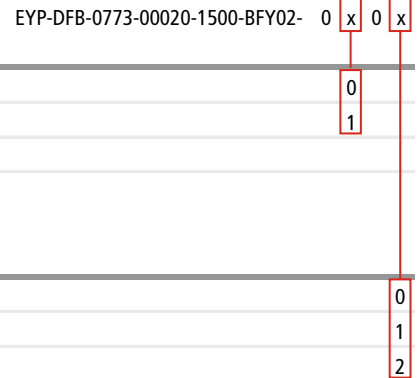
### Order Code Scheme

#### Connector

FC/APC (narrow key / 2mm)
SC/APC
other connector or fiber types upon request

#### Mode-hop free Tuning Range (Minimum Side Mode Suppression Ratio > 30 dB)

$P_{opt} = 20 \text{ mW};$	$T_{LD} = 25^\circ$	(Variant 0)
$P_{opt} = 5 \dots 20 \text{ mW};$	$T_{LD} = 25^\circ$	(Variant 1)
$P_{opt} = 5 \dots 20 \text{ mW};$	$T_{LD} = 15^\circ \dots 35^\circ \text{ C}$	(Variant 2)



### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB diode type is known to be sensitive against optical feedback, so an optical isolator may be required in some cases. Operating at moderate temperatures on a proper metal heat sinks will contribute to stable operation and a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

